











CSD17382F4

SLPS562 - APRIL 2016

CSD17382F4 30-V N-Channel FemtoFET™ MOSFET

Features

- Low On-Resistance
- Low Q_q and Q_{qd}
- Low Threshold Voltage
- Ultra-Small Footprint (0402 Case Size)
 - 1.0 mm × 0.6 mm
- Ultra-Low Profile
 - 0.35-mm Height
- Integrated ESD Protection Diode
 - Rated > 3-kV HBM
 - Rated > 2-kV CDM
- Lead and Halogen Free
- **RoHS Compliant**

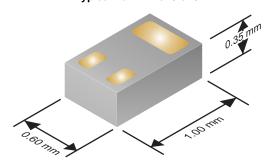
2 Applications

- Optimized for Load Switch Applications
- Optimized for General Purpose Switching **Applications**
- Single-Cell Battery Applications
- Handheld and Mobile Applications

3 Description

This 30-V, 54-mΩ, N-Channel FemtoFET™ MOSFET technology is designed and optimized to minimize the footprint in many handheld and mobile applications. This technology is capable of replacing standard small signal MOSFETs while providing at least a 60% reduction in footprint size.

Typical Part Dimensions



Product Summary

T _A = 25°	°C	TYPICAL VA	UNIT				
V_{DS}	Drain-to-Source Voltage 30						
Q_g	Gate Charge Total (4.5 V)	2.1		nC			
Q_{gd}	Gate Charge Gate-to-Drain	0.63	nC				
		V _{GS} = 1.8 V	110	mΩ			
	Drain-to-Source On-Resistance	V _{GS} = 2.5 V	67	mΩ			
R _{DS(on)}	Drain-to-Source On-Resistance	V _{GS} = 4.5 V 56		mΩ			
		$V_{GS} = 8.0 \text{ V}$	54	mΩ			
V _{GS(th)}	Threshold Voltage	0.9	V				

Ordering Information(1)

DEVICE	QTY	MEDIA	PACKAGE	SHIP
CSD17382F4	3000	7-Inch	Femto (0402) 1.0-mm ×	Tape and
CSD17382F4T	250	Reel	0.6-mm SMD Lead Less	Reel

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Absolute Maximum Ratings

$T_A = 25$	°C	VALUE	UNIT						
V_{DS}	Drain-to-Source Voltage	30	V						
V_{GS}	Gate-to-Source Voltage	10	V						
I _D	Continuous Drain Current ⁽¹⁾	2.3	Α						
I _{DM}	Pulsed Drain Current ⁽²⁾	14.8	Α						
P _D	Power Dissipation ⁽¹⁾	500	mW						
ESD	Human Body Model (HBM)	3000	V						
Rating	Charged Device Model (CDM)	2000	V						
T _J , T _{stg}	Operating Junction, Storage Temperature	-55 to 150	°C						
E _{AS}	Avalanche Energy, Single Pulse I_D = 6.5 A, L = 0.1 mH, R_G = 25 Ω	2.1	mJ						

- (1) Typical $R_{\theta JA} = 245^{\circ}C/W$ on $1-in^2$ (6.45-cm²), 2-oz. (0.071-mm) thick Cu pad on a 0.06-in (1.52-mm) thick FR4
- (2) Pulse duration ≤100 µs, duty cycle ≤1%.

Top View

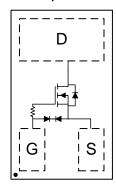






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4 Revision History

DATE	REVISION	NOTES
April 2016	*	Initial release.

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5 Specifications

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5.1 Electrical Characteristics

 $T_A = 25^{\circ}C$ (unless otherwise stated)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
STATIC	CHARACTERISTICS					
BV _{DSS}	Drain-to-source voltage	V _{GS} = 0 V, I _{DS} = 250 μA	30			V
I _{DSS}	Drain-to-source leakage current	V _{GS} = 0 V, V _{DS} = 24 V			1	μΑ
I _{GSS}	Gate-to-source leakage current	V _{DS} = 0 V, V _{GS} = 10 V			5	μΑ
V _{GS(th)}	Gate-to-source threshold voltage	$V_{DS} = V_{GS}, I_{DS} = 250 \mu A$	0.7	0.9	1.2	V
		V _{GS} = 1.8 V, I _{DS} =0.5 A		110	180	mΩ
D	Dunin to common our manietoures	$V_{GS} = 2.5 \text{ V}, I_{DS} = 0.5 \text{ A}$		67	82	mΩ
R _{DS(on)}	Drain-to-source on-resistance	$V_{GS} = 4.5 \text{ V}, I_{DS} = 0.5 \text{ A}$		56	67	mΩ
		$V_{GS} = 8.0 \text{ V}, I_{DS} = 0.5 \text{ A}$		54	64	mΩ
9 _{fs}	Transconductance	V _{DS} = 15 V, I _{DS} = 0.5 A		5.9		S
DYNAMI	C CHARACTERISTICS					
C _{iss}	Input capacitance		347	pF		
C _{oss}	Output capacitance	$V_{GS} = 0 \text{ V}, V_{DS} = 15 \text{ V},$ f = 1 MHz		31.0	40.3	pF
C _{rss}	Reverse transfer capacitance	<i>y</i> = 1 (VII 12		15.0	19.5	pF
R_G	Series gate resistance			220		Ω
Qg	Gate charge total (4.5 V)			2.1	2.7	nC
Q _{gd}	Gate charge gate-to-drain	V 45 V 1 0 5 A		0.63		nC
Q _{gs}	Gate charge gate-to-source	V _{DS} = 15 V, I _{DS} = 0.5 A		0.41		nC
Q _{g(th)}	Gate charge at V _{th}			0.12		nC
Q _{oss}	Output charge	V _{DS} = 15 V, V _{GS} = 0 V		1.53		nC
t _{d(on)}	Turn on delay time			59		ns
t _r	Rise time	V _{DS} = 15 V, V _{GS} = 4.5 V,		111		ns
t _{d(off)}	Turn off delay time	$I_{DS} = 0.5 \text{ A}, R_G = 0 \Omega$		279		ns
t _f	Fall time	270				ns
DIODE C	CHARACTERISTICS		-		'	
V _{SD}	Diode forward voltage	$I_{SD} = 0.5 \text{ A}, V_{GS} = 0 \text{ V}$		0.7	1.0	V

5.2 Thermal Information

 $T_A = 25$ °C (unless otherwise stated)

	THERMAL METRIC	TYPICAL VALUES	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance ⁽¹⁾	85	°C/W
	Junction-to-ambient thermal resistance ⁽²⁾	245	°C/W

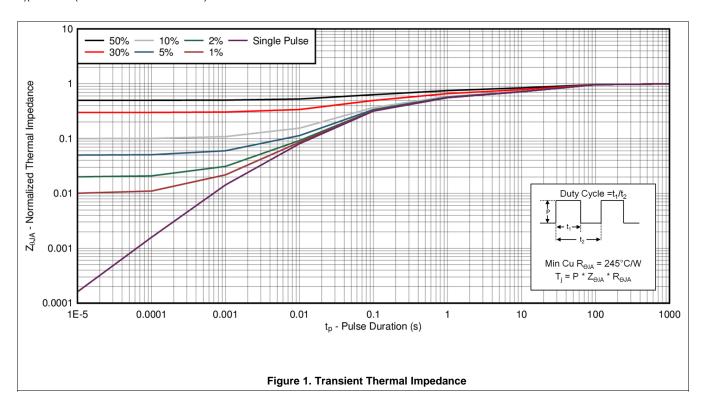
⁽¹⁾ Device mounted on FR4 material with 1-in² (6.45-cm²), 2-oz. (0.071-mm) thick Cu.

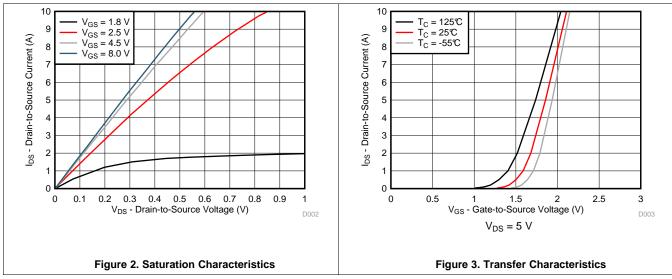
⁽²⁾ Device mounted on FR4 material with minimum Cu mounting area.

TEXAS INSTRUMENTS

5.3 Typical MOSFET Characteristics

 $T_A = 25$ °C (unless otherwise stated)



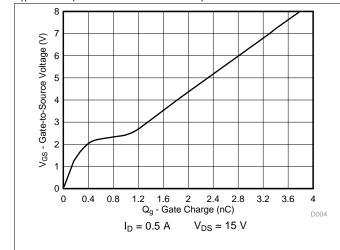




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Typical MOSFET Characteristics (continued)

 $T_A = 25$ °C (unless otherwise stated)



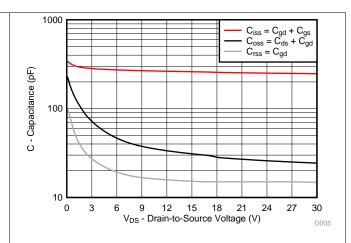


Figure 4. Gate Charge

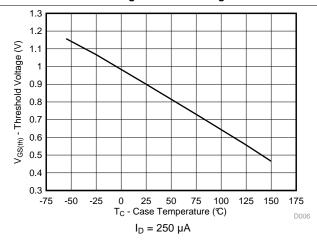


Figure 5. Capacitance

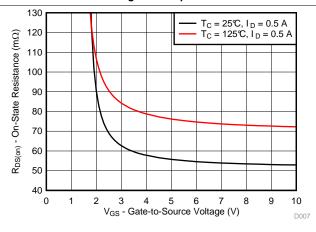
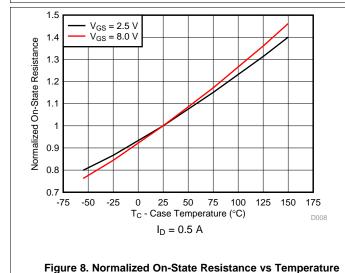


Figure 6. Threshold Voltage vs Temperature

Figure 7. On-State Resistance vs Gate-to-Source Voltage



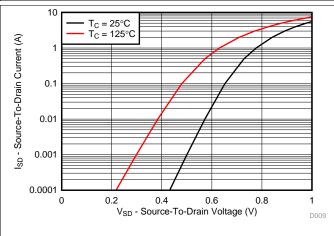


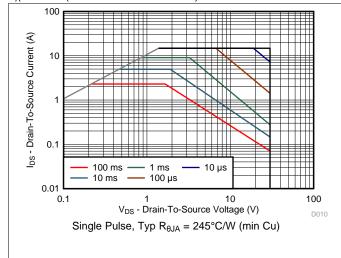
Figure 9. Typical Diode Forward Voltage

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Typical MOSFET Characteristics (continued)

 $T_A = 25$ °C (unless otherwise stated)



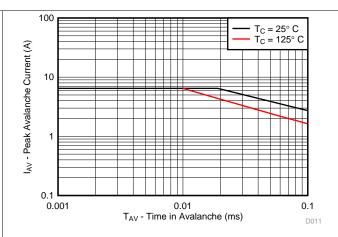


Figure 10. Maximum Safe Operating Area (SOA)

Figure 11. Single Pulse Unclamped Inductive Switching

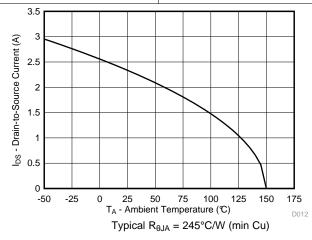


Figure 12. Maximum Drain Current vs Temperature

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6 Device and Documentation Support

6.1 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of

TI E2E™ Online Community T's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support TI's Design Support Quickly find helpful E2E forums along with design support tools and contact information for technical support.

6.2 Trademarks

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6.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

6.4 Glossary

SLYZ022 — TI Glossarv.

This glossary lists and explains terms, acronyms, and definitions.

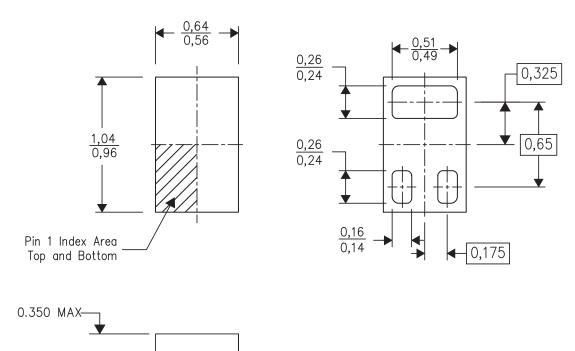
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7 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

7.1 Mechanical Dimensions

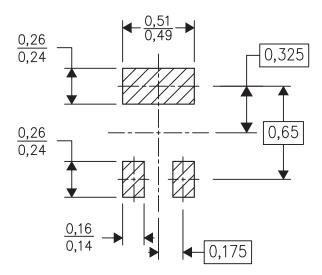


- (1) All linear dimensions are in millimeters (dimensions and tolerancing per AME T14.5M-1994).
- (2) This drawing is subject to change without notice.
- (3) This package is a PB-free solder land design.



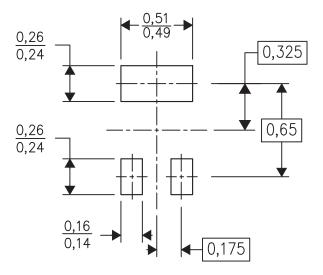
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7.2 Recommended Minimum PCB Layout



(1) All dimensions are in millimeters.

7.3 Recommended Stencil Pattern

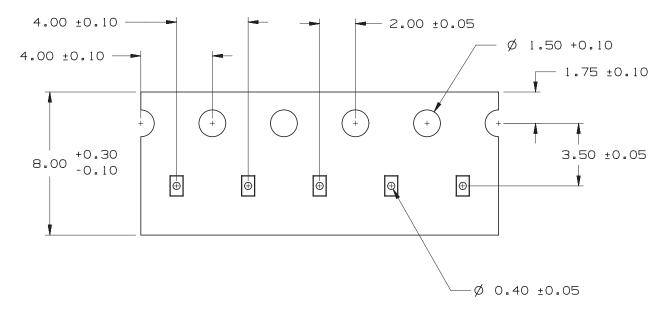


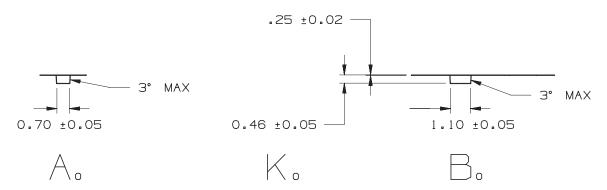
(1) All dimensions are in millimeters.

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7.4 CSD17382F4 Embossed Carrier Tape Dimensions





(1) Pin 1 is oriented in the top-right quadrant of the tape enclosure (quadrant 2), closest to the carrier tape sprocket holes



PACKAGE OPTION ADDENDUM

12-Apr-2016

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty		Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		J			(2)	(6)	(3)		(4/5)	
CSD17382F4	ACTIVE	PICOSTAR	YJC	3	3000	Green (RoHS & no Sb/Br)	Call TI	Level-1-260C-UNLIM	-55 to 150	HM	Samples
CSD17382F4T	ACTIVE	PICOSTAR	YJC	3	250	Green (RoHS & no Sb/Br)	Call TI	Level-1-260C-UNLIM	-55 to 150	НМ	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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- Подбор аналогов;
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